



# Vanadium-based cathodes for aqueous zinc ion batteries: Structure, mechanism and prospects

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## ABSTRACT

As an emerging energy storage device with high-safety aqueous electrolytes, low-cost, environmental benignity and large-reserves, the rechargeable aqueous zinc-ion batteries (AZIBs) have attracted more and more attention. Vanadium-based compounds are also supposed as the potential candidate cathode materials for AZIBs due to their wide variety of phases, variable crystal structures and high theoretical capacity. In this review, the recent progress in the development of vanadium-based materials was summarized, and the relationship between the crystal structure types of active materials and Zn-ion transport mechanism was highlighted. During the charge-discharge process, the different electrostatic repulsion between the cations of vanadium-based compounds with different crystal structures and  $\text{Zn}^{2+}$  results in a variety of the Zn-ion storage mechanisms, which can be significant guidance for designing the advanced battery-electrode materials for AZIBs. Furthermore, other factors associated with the storage mechanisms, such as electrolyte components and electrode morphology, are discussed. Finally, the strategies to improve the electrical conductivity, inhibit the dissolution and stabilize the crystal structure of vanadium-based compounds are proposed and the future prospects for developing high-energy-density AZIBs are presented.

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## 1. Introduction

In recent years, the demands for electric energy are growing day by day with the development of economic society and industrial civilization. The declining of traditional fossil energy sources forces people to turn their attention to renewable clean energy resources [1]. However, the energy output of renewable clean energy resources is intermittent, which is difficult to meet the customer requirements. So the reliable and efficient electrical energy storage systems (EESS) are considered as a key support to solve the problem of unstable new energy power generation [2]. The ideal EEES possess the following characteristics: pollution-free, high reliability, low cost, high safety, long cycle life, high gravimetric energy, high energy efficiency, and high power density [3]. Lithium-ion batteries with higher energy density (150–265 Wh/kg) have become the star performer of EEES [4,5], which change the communication ways and the power supply for portable equipment [6–8]. But “Lithium dendrites” formed on the surface of negative electrodes can penetrate the diaphragm, causing an electrical short circuit. And the use of highly-flammable organic electrolytes has a huge negative impact on the safety of lithium-ion batteries. Beside,

the cost of manufacturing lithium-ion batteries has been rising. Therefore, rechargeable aqueous metal-ion batteries are brought into focus due to their high safety and low cost.

Aqueous zinc ion batteries (AZIBs) stand out from numerous rechargeable aqueous metal-ion batteries due to its various advantages, such as high theoretical capacity (820 mAh/g or 5855 mAh/cm<sup>3</sup>), low redox potential (−0.762 V vs. standard hydrogen electrode), high stability and abundant zinc resources [9–14]. However, many cathode materials paired with zinc anode face more problems including low specific capacity, low lifespan and high solubility [15–17], which can greatly affect the overall electrochemical performances of AZIBs. The commercial success of alkaline zinc-manganese dioxide batteries has led to the rapid development of rechargeable Zn-MnO<sub>2</sub> batteries [18–21]. However, the volume expansion and poor conductivity of MnO<sub>2</sub>, and the formation of irreversible electrochemical-inert products during the charge/discharge process reduce the capacity of Zn-MnO<sub>2</sub> batteries and shorten its lifespan [22–25]. Whereafter a variety of cathode materials for AZIBs including vanadium-based derivatives [26–28], Prussian blue analogs (PBAs) [29], and organic compounds [30] are gradually developed. There are few studies on PBAs materials due to their limited capacity (<150 mAh/g), the oxygen evolution reaction under high operating voltage [31–33] and organic compounds owing to the dissolution in the aqueous electrolyte.

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Vanadium-based compounds have the characteristics of multiple oxidation states, variable crystal structures, high theoretical capacity (>300 mAh/g), and highly abundant element in the Earth's crust, which has become a research hotspot [34–39].

In this review, the latest investigations of Zn-ion storage mechanism based on the crystal structures of vanadium-based cathodes was summarized. The flexible  $\text{VO}_x$  polyhedron unit in vanadium-based compounds can be assembled into various open structures such as 1D tunnel, 2D layer and 3D framework by means of different connections to allow for the reversible de/insertion of zinc ions. Additionally, the cations in vanadates as “pillars” can optimize the layer distance to improve the electrochemical performances of AZIBs. The inductive effect of  $[\text{PO}_4]$  tetrahedron in alkali vanadium phosphates can also provide a higher operating voltage for  $\text{Zn}^{2+}$  storage. Such variable crystal structures endow vanadium-based compounds excellent electrochemical performance. However, most V-compounds face some problems in inherently poor electrical conductivity, poor structure stability and vanadium dissolution. Finally, the modification strategies for vanadium dissolution and structural instability are proposed for high-performance AZIBs.

## 2. Vanadium-based materials

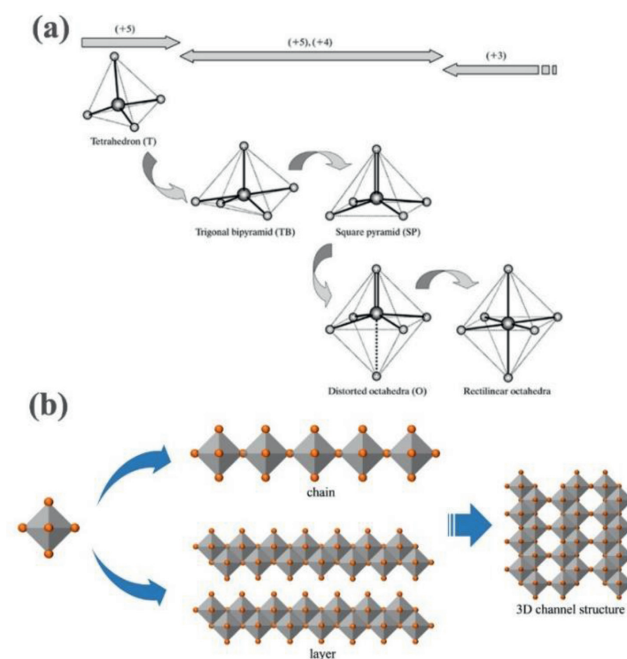
Vanadium-based materials are very competitive candidates for AZIBs cathodes. Variable ion diffusion channels of vanadium-based materials affect the electrochemical activity of active materials. At present, there are various types of energy storage mechanisms for AZIBs including  $\text{Zn}^{2+}$  insertion,  $\text{H}^+$  insertion,  $\text{Zn}^{2+}/\text{H}^+$  co-insertion,  $\text{Zn}^{2+}/\text{H}_2\text{O}$  co-insertion and chemical conversion reactions. In this section, the vanadium-based materials are classified based on the material types and their storage mechanisms are discussed based on crystal structures.

### 2.1. Introduction of vanadium oxides in AZIBs

Vanadium has 5 valence electrons that can be lost, so it has the ability to adopt multi-oxidation states (from +2 to +5) and to form numerous complexes. The vanadium-oxygen coordination polyhedron in vanadium oxides varies with their oxidation states from tetrahedron through trigonal bipyramid and square pyramid to distorted octahedra and rectilinear octahedra (Fig. 1a), in which the oxidation state of vanadium atom decreases from +5 through +5/+4 to +3 valence [40]. These polyhedrons link to form the chain structure by sharing corner, which link in turn into layers and then three-dimensional (3D) frameworks (Fig. 1b). These open structures can provide a variety of channels for  $\text{Zn}^{2+}$  insertion/extraction [41,42].

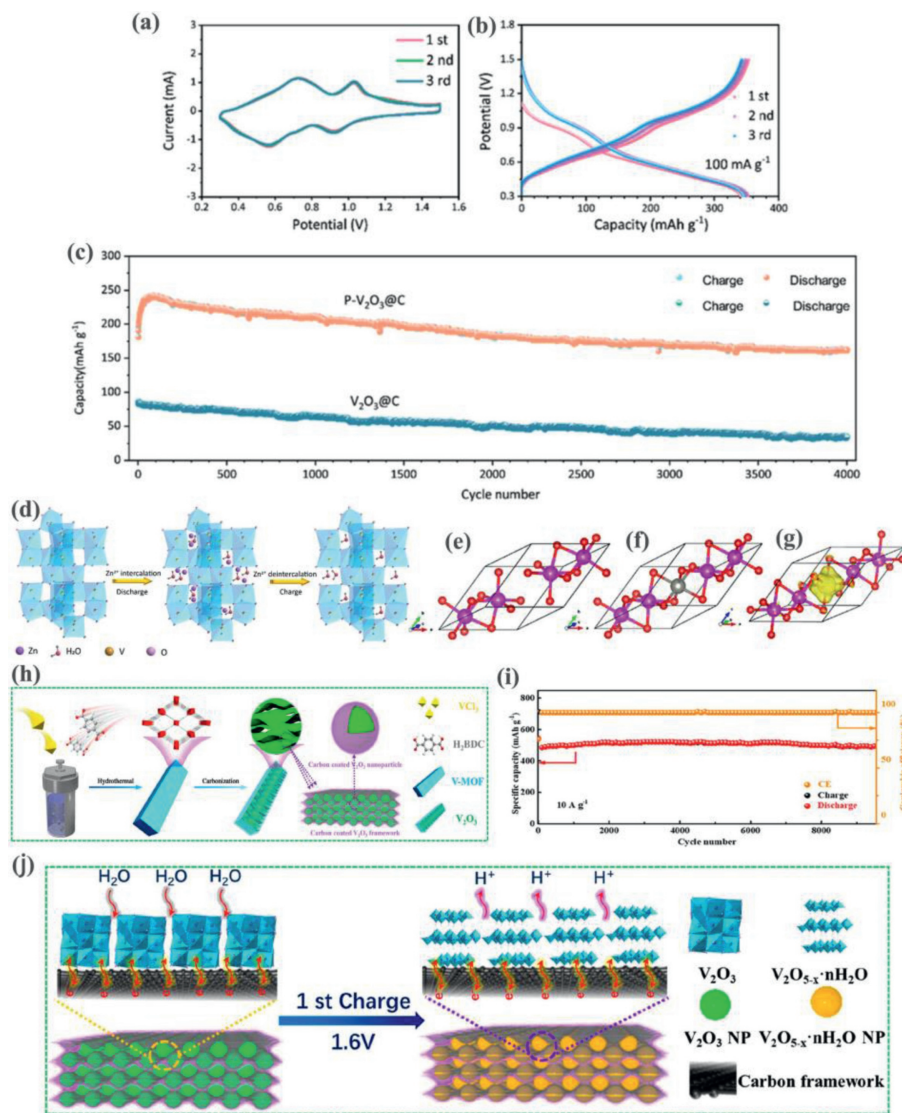
#### 2.1.1. Vanadium sesquioxides ( $\text{V}_2\text{O}_3$ )

The trigonal phase  $\text{V}_2\text{O}_3$  ( $R\bar{3}c$ ) has a 3D framework structure, which allows 3d electrons to move back and forth through the V-V chain followed by displaying metallic behavior. V atoms occupy two-thirds of octahedral interstices of O atoms, meanwhile two  $[\text{VO}_6]$  octahedrons link by sharing corner, face and edge with the adjacent one to form a tunnel-like 3D structure ( $0.288 \times 0.291 \times 0.291 \times 0.410 \text{ nm}^4$  along the (111) lattice plane). These tunnel structures are conducive to the insertion/extraction of metal ions, so  $\text{V}_2\text{O}_3$  materials are often used as electrode materials in electrochemical energy storage. Ding *et al.* [43] firstly applied porous  $\text{V}_2\text{O}_3$  pyrolyzed from vanadium-based MOFs precursors as cathode of AZIBs. The cyclic voltammetry (CV) plot in Fig. 2a shows two coupled redox peaks at 0.92/1.04 and 0.56/0.72 V, which involved the two-step de/insertion reaction of  $\text{Zn}^{2+}$ . This electrode displays a specific capacity of 300 mAh/g at 100 mA/g calculated based on Fig. 2b and also exhibits outstanding cycling stability with a capacity retention of 90% after 4000 cycles at



**Fig. 1.** (a) Coordination polyhedrons of vanadium with different valences. Reproduced with permission [40]. Copyright 1999, International Union of Crystallography. (b) The vanadium coordination polyhedron from chains → layers → 3D frameworks by sharing vertices or edges.

5 A/g (Fig. 2c). *Ex-situ* X-ray photoelectron spectroscopy (XPS), X-ray diffraction (XRD), and Raman tests were adopted to analyze the  $\text{Zn}^{2+}$ -storage mechanism. In the discharge cycle,  $\text{H}_2\text{O}$  molecules along with  $\text{Zn}^{2+}$  were migrated into the tunnel structures of  $\text{V}_2\text{O}_3$  and then were leftover in the charge process, which would help to expand the ion diffusion channel and reduce the diffusion resistance of  $\text{Zn}^{2+}$  (Fig. 2d). The first-principle calculation further confirmed that the intercalated- $\text{Zn}^{2+}$  occupied the octahedral interstices of O atoms to form a stable structure (Figs. 2e and f). The differential charge state density in Fig. 2g showed a chemical bond formation between  $\text{Zn}^{2+}$  and  $\text{O}^{2-}$  from  $\text{V}_2\text{O}_3$ . The inserted  $\text{Zn}^{2+}$  reduced the distance and strengthened the interaction between the two atoms, resulting in the improved cycle stability of AZIBs. However, the octahedral interstice was not large enough for more than one zinc ion storage, which was confirmed by the corresponding calculation results. Subsequently, Ding *et al.* [44] found that the vanadium vacancies could also facilitate the  $\text{Zn}^{2+}$  intercalation/extraction tested *via* operando XRD and Raman analysis. Defect-rich  $\text{V}_2\text{O}_3$  obtained from  $\text{V}_2\text{O}_5$  nanosheets calcinated in  $\text{NH}_3/\text{Ar}$  atmosphere by *in-situ* electrochemical lattice conversion reactions. Defect-rich  $\text{V}_2\text{O}_3$  as cathode achieved a high capacity of 382.5 mAh/g and a remarkable rate performance. In the first charge process, the lattice structure of  $\text{V}_2\text{O}_3$  was distorted to obtain vanadium vacancies, which were favorable for the  $\text{Zn}^{2+}$  de/intercalation in the subsequent cycles. The activated  $\text{V}_2\text{O}_3$  by fabricating the vanadium vacancies could fasten the reaction kinetics of AZIBs, but the detailed reaction mechanism was still unclear. Luo *et al.* [45] investigated the reaction mechanism of fastening the electrochemical kinetics by preparing hollow-carved carbon-coated  $\text{V}_2\text{O}_3$  microcuboids with abundant channels, short ion diffusion distance and good electrical conductivity (Fig. 2h). The electrolyte concentration played an important role in the electrochemical performance of  $\text{V}_2\text{O}_3$  electrodes. The capacity and cycle stability in 2 mol/L  $\text{Zn}(\text{CF}_3\text{SO}_3)_2$  were superior to those of 1, 3 and 4 mol/L. The maximum capacity, high rate performance and capacity retention in 2 mol/L electrolyte was 625 mAh/g at 0.1 A/g,



**Fig. 2.** (a) CV at 0.2 mV/s between 0.3 V and 1.5 V and (b) charge/discharge curves (GCD) for the initial three cycles of the porous  $V_2O_3@C$  microspheres (P- $V_2O_3@C$ ). (c) Long-term cycling performance at 5 A/g. (d) Schematic diagram of  $Zn^{2+}$  storage mechanism, structure of  $V_2O_3$  without (e) and with (f)  $Zn^{2+}$  being inserted. (g) Differential charge state density between  $V_2O_3$  with the inserted Zn ions. Reproduced with permission [43]. Copyright 2019, American Chemical Society. (h) The preparation schematic illustration of the hierarchical carbon-coated  $V_2O_3$ . (i) Long-cycling performance of  $V_2O_3$  in 2 mol/L  $Zn(CF_3SO_3)_2$ . (j) The oxidation schematic illustration of  $V_2O_3$  during the first charging. Reproduced with permission [45]. Copyright 2020, American Chemical Society.

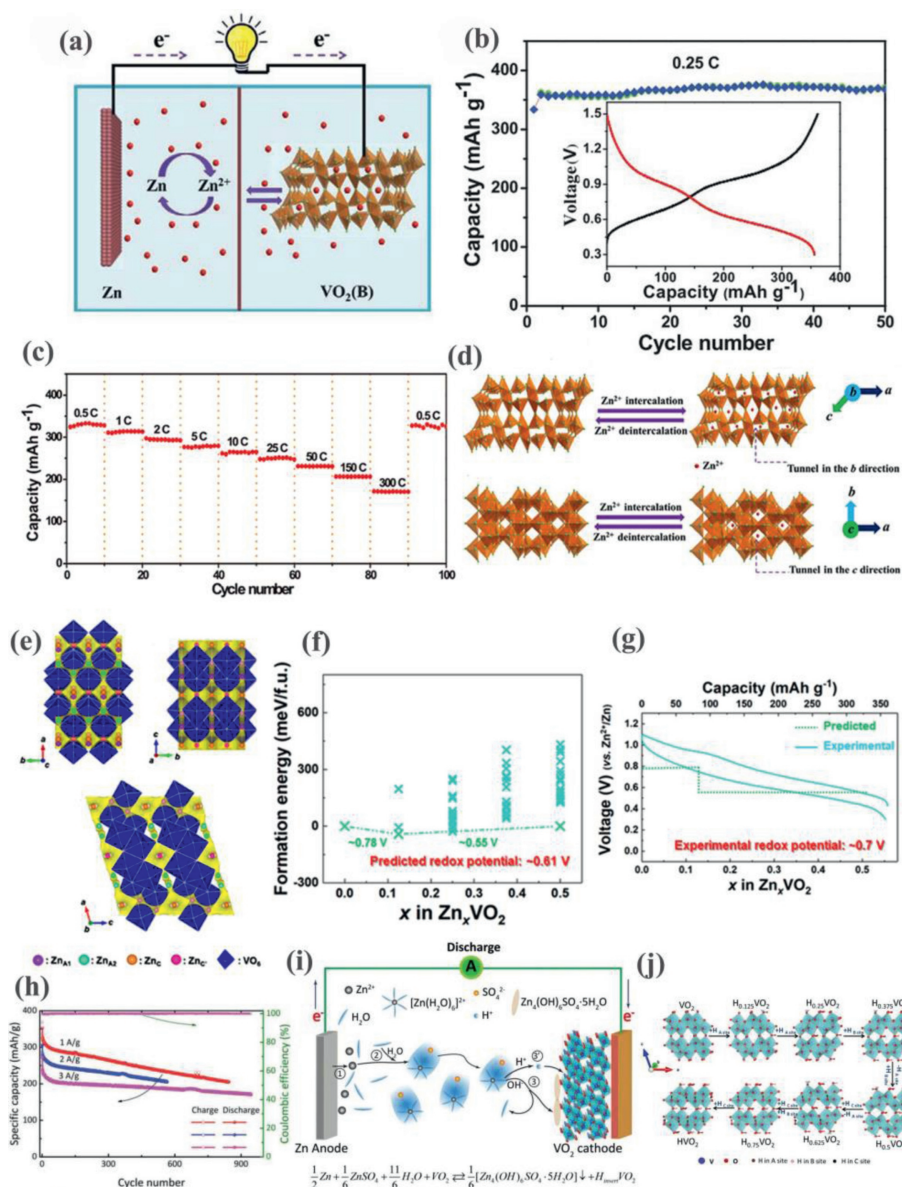
486 mAh/g at 20 A/g, and 100% after 10,000 cycles, respectively (Fig. 2i).  $H_2O$  as reductant provided the electron to  $V_2O_3$  to form  $V_{10}O_{24} \cdot 12H_2O$  (Fig. 2j) in the initial charge process, and then layer  $Zn_{3+x}(OH)_{2+3x}V_{2-x}O_{7-3x} \cdot 2H_2O$  appeared in the subsequent discharge process.  $V_{10}O_{24} \cdot 12H_2O$  and  $Zn_{3+x}(OH)_{2+3x}V_{2-x}O_{7-3x} \cdot 2H_2O$  gradually were converted into  $V_2O_5 \cdot nH_2O$  and  $Zn_xV_2O_5 \cdot nH_2O$ , respectively after 20<sup>th</sup> charging/discharging.

### 2.1.2. Vanadium dioxide ( $VO_2$ )

$VO_2$  phase with different space groups (B ( $C2/m$ ), M ( $P2_1/c$ ), A ( $P4_2/nmc$ ), D ( $P2_1/c$ )) has been widely studied as the cathode material for AZIBs. The  $[VO_6]$  octahedron as the basic structural unit of the above-mentioned four phases links by edge or vertice to form a tunnel structure. The two octahedrons of  $VO_2(B)$  connect along the  $b$ -axis direction and the second layer moves  $(1/2, 1/2, 0)$  (fractional coordinates in unit cell) relative to the first layer, shaping into a tunnel structure. The V-V atoms in monoclinic  $VO_2(M)$  form a zigzag-chain structure along the  $c$  axis, causing a staggered transverse displacement of vanadium atoms and an oxygen octahedron

distortion. Hence,  $VO_2(M)$  has denser tunnels than  $VO_2(B)$ . Similar to the  $VO_2(M)$  structure,  $VO_2(D)$  is built based on one chain composed of alternating the edge-sharing distorted  $[V(1)O_6]$  octahedron linking to another individual chain composed of  $[V(2)O_6]$  octahedron through corner-shared oxygen atoms. For  $VO_2(A)$ , four sets of two-sided octahedrons on the  $c$  plane form a  $2 \times 2$  square. These squares stack along the  $c$  axis by edge-sharing to form long Z-shaped V-atom chains.

$VO_2(B)$  is suitable for use as the electrode materials of AZIBs due to higher theoretical capacity and the tunnel structure with plus sizes (0.34, 0.82 and 0.5 nm<sup>3</sup> along  $a$ -,  $b$ - and  $c$ -axes, respectively) for the  $Zn^{2+}$  migration. Ding *et al.* [46] investigated the interaction behavior of  $Zn^{2+}$  with  $VO_2(B)$  in AZIBs assembled with  $VO_2(B)$  nanofibers as cathode, Zn foil as anode, and  $Zn(CF_3SO_3)_2$  as electrolyte (Fig. 3a).  $VO_2(B)$  cathode displayed a specific capacity of 357 mAh/g (Fig. 3b) and superior rate capability (171 mAh/g at 51.2 A/g in Fig. 3c), ascribing to the intercalation pseudocapacitance behavior and the ultrafast kinetics of  $Zn^{2+}$  into the tunnel structures of  $VO_2(B)$ . The lattice parameter variation with the



**Fig. 3.** (a) Schematic of AZIB with  $\text{VO}_2(\text{B})$  nanowire as cathode and Zn foil as anode. (b) Cycling performance of  $\text{VO}_2(\text{B})$  cathode at 0.25 C (additional: GCD curve). (c) Rate capabilities of  $\text{VO}_2(\text{B})$  nanofibers. (d) Schematic view of  $\text{Zn}^{2+}$  insertion/extraction  $\text{VO}_2(\text{B})$  nanofibers projected along the direction of the  $b$  and  $c$  axes, respectively. Reproduced with permission [46]. Copyright 2018, Wiley-VCH. (e) Bond-valence sum energy map of  $\text{VO}_2(\text{B})$  for the  $a$ - $b$ ,  $b$ - $c$ , and  $a$ - $c$  planes showing all possible Zn-ion sites in the  $\text{VO}_2(\text{B})$  structure. (f) Formation energy of  $\text{Zn}_x\text{VO}_2(\text{B})$  ( $0 \leq x \leq 0.5$ ). (g) Calculated average redox potential and experimentally measured charge/discharge curve of  $\text{Zn}_x\text{VO}_2(\text{B})$ . Reproduced with permission [47]. Copyright 2018, American Chemical Society. (h) Cycling performance and the corresponding coulombic efficiency of  $\text{VO}_2$  nanorods under different current densities. (i) Diagram of electrochemical mechanism during discharge of Zn/ $\text{VO}_2$  battery. (j) The sequential insertion of  $\text{H}^+$  into the  $\text{VO}_2$ . Reproduced with permission [49]. Copyright 2019, Wiley-VCH.

$\text{Zn}^{2+}$  intercalation into the tunnels (paralleled to the  $b$ - and  $c$ -axes of  $\text{VO}_2(\text{B})$ ) tested by *in-situ* XRD diffraction was less, suggesting that these tunnels were stable and large enough to ensure the fast  $\text{Zn}^{2+}$  intercalation/de-intercalation (Fig. 3d). Therefore,  $\text{VO}_2(\text{B})$  cathode with tunnel-structure was proved feasible to permit the insertion/extraction of  $\text{Zn}^{2+}$  in laboratory-scale research. Park *et al.* [47] further revealed the electrochemical reaction mechanism of AZIBs using a bond-valence sum energy map and a first-principle calculation. Among the four sites ( $\text{Zn}_c$ ,  $\text{Zn}_{A1}$ ,  $\text{Zn}_{A2}$ ,  $\text{Zn}_c$ ) of inserting  $\text{Zn}^{2+}$  into  $\text{VO}_2(\text{B})$  structure shown in Fig. 3e,  $\text{Zn}_{A2}$  site was the optimal location of  $\text{Zn}^{2+}$  into  $\text{VO}_2(\text{B})$  and the predicted redox potential of  $\text{Zn}_x\text{VO}_2(\text{B})$  was  $\sim 0.61$  V (Fig. 3f), close to the experimental value of  $\sim 0.7$  V ( $\text{VO}_2(\text{B}) + 0.57\text{Zn}^{2+} + 1.14\text{e}^- \leftrightarrow \text{Zn}_{0.57}\text{VO}_2(\text{B})$ , Fig. 3g). The pseudocapacitance contribution of  $\text{Zn}^{2+}$  intercalating into  $\text{VO}_2(\text{B})$  structure, evaluated using potentiodynamic elec-

trochemical impedance spectroscopy (PDEIS) technique was negligible. But the strong Coulombic ion-lattice interaction between  $\text{Zn}^{2+}$  and  $\text{VO}_2(\text{B})$  structure slowed down the kinetics and further limited the improvement of electrochemical properties. Oxygen-deficient  $\text{VO}_2$  nanostructure could address the above-mentioned problem through providing the jumping charge transport sites *via* enlarging the  $b$  tunnels for fast zinc-ion diffusion.  $\text{VO}_2$  with high-concentration oxygen vacancies prepared by Li *et al.* [48] displayed a discharge specific capacity of 375 mAh/g at 100 mA/g and long-term cyclic stability with a retained capacity of 175 mAh/g at 5 A/g over 2000 cycles in 3 mol/L  $\text{Zn}(\text{CF}_3\text{SO}_3)_2$ . However, in aqueous electrolytes,  $\text{Zn}^{2+}$  often exists in the form of  $\text{Zn}(\text{H}_2\text{O})_6^{2+}$ , indicating that larger desolvation energy and insertion energy need to be overcome in the process of  $\text{Zn}^{2+}$  insertion. And the strong electrostatic repulsion between  $\text{Zn}^{2+}$  and host structure also causes

poor diffusion kinetics and mild deformation in the host structure. So Li *et al.* [49] announced a  $H^+$  (de)insertion mechanism with less structure distortion of  $VO_2(B)$  than the  $Zn^{2+}$  insertion mechanism. The  $VO_2(B)$  cathode exhibited excellent electrochemical performances of the first discharge capacity (353 mAh/g at 1.0 A/g), a 75.5% capacity retention after 945 cycles at 3.0 A/g in 1 mol/L  $ZnSO_4$  (Fig. 3h). The whole reaction steps were shown in Fig. 3i. The generated  $H^+$  in the deposition process of  $Zn_4(OH)_6SO_4 \cdot 5H_2O$  could insert into  $VO_2(B)$  to contribute most of capacity by the first-principle analysis (Fig. 3j) and keep long-term cycle stability. Zhang *et al.* [50] further verified the proton insertion mechanism by the bond valence method using  $VO_2(M)$  as cathode and  $ZnSO_4$  as electrolyte. While storing  $Zn^{2+}$  in  $VO_2(D)$  phase,  $H^+$  and  $Zn^{2+}$  could simultaneously insert into and extract from  $VO_2(D)$  during the cycling process, resulting in a phase transition from  $VO_2(D)$  to  $V_2O_5 \cdot xH_2O$  [51].  $H_2O$  molecules with  $Zn^{2+}$  co-intercalation into host structure facilitated the intercalation of  $Zn^{2+}$  due to shielding the electrostatic interactions between charge carrier and  $VO_2(D)$ .

### 2.1.3. Vanadium (IV, V) oxide ( $V_6O_{13}$ )

The monoclinic  $V_6O_{13}$  ( $C2/m$ ) with mixed-valence vanadium ( $V^{4+}/V^{5+}$ ) consists of alternating single- and double-layer distorted  $[VO_6]$  octahedrons connected by sharing corner to form chains zigzag along the  $b$ -axis [52], which can provide more active sites for ion storage (such as  $Li^+$  capacity: 417 mAh/g) [53,54]. As shown in Fig. 4a, the valence states of V(1) atoms in single-layer and V(3) atoms in double-layer are +4, while the valence state of V(2) atoms in the double layer is +5. So the ratio of  $V^{4+}/V^{5+}$  is 2:1 and an average mixed vanadium valence is  $V^{4.33+}$  [55]. Moreover,  $V_6O_{13}$  at room temperature has a metallic character.

Shan *et al.* [56] prepared  $V_6O_{13}$  cathode and investigated the  $Zn^{2+}$  storage mechanism in AZIBs. The  $V_6O_{13}$  electrode displayed a specific capacity of 206 mAh/g at 10 A/g after 3000 cycles and an excellent rate performance owing to higher  $Zn^{2+}$  ion diffusion coefficient, better electronic conductivity than  $V_2O_5$  and  $VO_2$  (Figs. 4b and c). Interestingly, the highly-reversible  $Zn_{0.25}V_2O_5 \cdot H_2O$  phase promoted the storage of  $Zn^{2+}$  verified by *ex-situ* XRD, high-resolution transmission electron microscope (HRTEM) and XPS (Fig. 4d). Fig. 4e illustrates the  $Zn^{2+}$  insertion/extraction mechanism. During the discharge process of aqueous  $Zn/V_6O_{13}$  cell,  $Zn^{2+}$  is inserted into the empty sites of  $V_6O_{13}$  phase to form a new  $Zn_{0.25}V_2O_5 \cdot H_2O$  phase; while in the subsequent charge process,  $Zn^{2+}$  is extracted from  $V_6O_{13}$  and  $Zn_{0.25}V_2O_5 \cdot H_2O$  phase simultaneously disappears. A structural engineering strategy of oxygen-deficient is usually adopted to fasten the kinetics and boost the  $Zn^{2+}$  diffusion pathways for the reversibility and capacity of  $V_6O_{13}$  cathode. As an example, the oxygen-deficient  $V_6O_{13}$  structure was fabricated by a two-step method from solution-redox-based self-assembly method to thermal treatment under a reducing  $N_2/H_2$  atmosphere, which was explored to create more  $Zn^{2+}$  intercalating sites [57]. The resulting  $V_6O_{13}$  cathode retained a high specific capacity of 400 mAh/g after 200 cycles, reaching a utilization rate of 95% of the theoretical specific capacity. Its capacity retention still remained 86% after 2000 cycles because the vacancies of  $V_6O_{13}$  provided more pathways of  $Zn^{2+}$ . The surface electron density difference analysis proved that the charge distributions of oxygen-deficient  $V_6O_{13}$  structure in Figs. 4h and i were more concentrated than those of perfect  $V_6O_{13}$  in Figs. 4f and g, resulting in the dual-direction  $Zn^{2+}$  insertion formation and the capacity increase. As we all know, the strong electrostatic attraction between  $Zn^{2+}$  and host structure could hinder the  $Zn^{2+}$  diffusion, so  $CO_2$ -trapped in  $V_6O_{13}$  was designed to modify the electrochemical performance [58]. The as-prepared  $CO_2$ - $V_6O_{13}$  electrode showed a maximum capacity of 471 mAh/g (Fig. 4j) and an excellent cyclic stability of 80% capacity retention after 4000 cycles at 2 A/g (Fig. 4k).

### 2.1.4. Vanadium pentoxide ( $V_2O_5$ )

The layered orthorhombic  $V_2O_5$  structure (Pmmn) is build-up of zigzag double chains of edge and corner sharing distorted  $[VO_5]$  square pyramids. The layers are connected along the  $c$ -axis by weak electrostatic interactions, which are readily available for the intercalation of  $Zn^{2+}$ . The interlayer spacing of 0.577 nm in  $V_2O_5$  is much larger than the radius of  $Zn^{2+}$  (0.074 nm), so it can deliver a high theoretical capacity of 589 mAh/g.

Zhang *et al.* [36] assembled AZIBs based on ball-milled commercial  $V_2O_5$  cathode, Zn anode and 3 mol/L  $Zn(CF_3SO_3)_2$  electrolyte, whose reversible capacity reached 470 mAh/g at 0.2 A/g (Fig. 5a) and capacity retention was 91.1% over 4000 cycles at 5 A/g (Fig. 5b). Chen *et al.* [59] prepared porous  $V_2O_5$  nanofibers (Fig. 5c) by electrospinning technology, which displayed the capacity of 319 mAh/g at 20 mA/g and capacity retention of 81% over 500 cycles at 2 C (Fig. 5d) in  $Zn(CF_3SO_3)_2$  electrolyte. A two-step conversion mechanism was adopted to explain the  $Zn^{2+}$  insertion/extraction (Fig. 5e): the open-structured zinc pyrovanadate ( $Zn_{3+x}(OH)_2V_2O_7 \cdot 2H_2O$ ) formation in the first discharge and then the reversible insertion/extraction of  $Zn^{2+}$  between  $Zn_{3+x}(OH)_2V_2O_7 \cdot 2H_2O$  and  $Zn_{3+y}(OH)_2V_2O_7 \cdot 2H_2O$ . Optimizing electrode manufacture is an effective strategy to enhance the specific capacity of active materials. Javed *et al.* [60] directly grew 2D  $V_2O_5$  nanosheets on Ti substrate to increase the contact between  $V_2O_5$  and collector to avoid agglomeration, which as cathode exhibited a discharge capacity of 503.1 mAh/g at 100 mA/g and long-term stability with 86% retention after over 700 cycles at 500 mA/g.

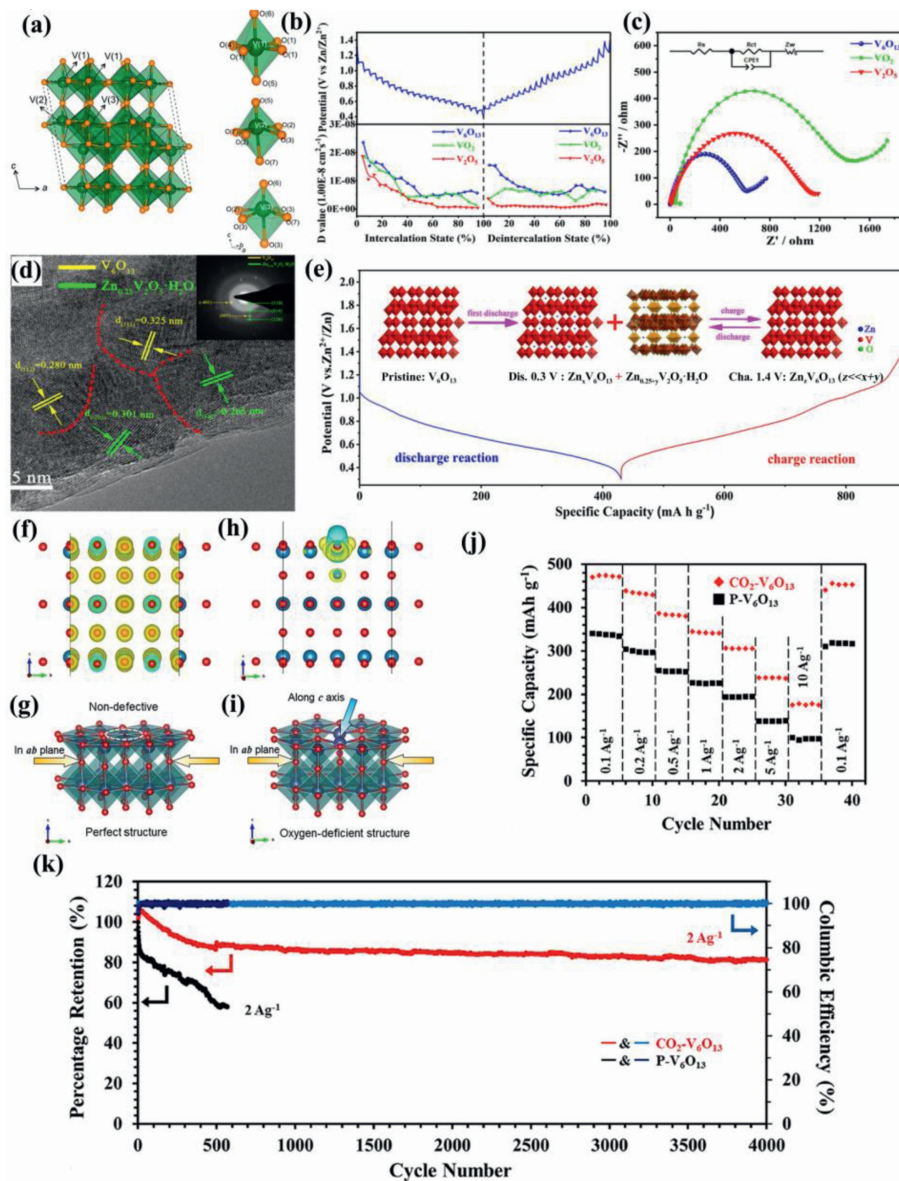
The pre-intercalation of light alkali metal ions into  $V_2O_5$  structure was also an effective strategy to improve the electrochemical properties through enlarging the interlayer distance. For instance,  $Na_{0.3}V_2O_5$  nanowire cathode had a high capacity of 367.1 mAh/g at 0.1 A/g and its capacity retention reached 93% after 1000 cycles in  $Zn/Na_{0.3}V_2O_5$  batteries [61]. The  $Na^+$  as "pillars" between  $V_2O_5$  layers not only enhanced the conductivity of  $V_2O_5$  but also improved the structural stability of  $V_2O_5$  structure during the  $Zn^{2+}$  insertion/extraction. The incorporation of  $K^+$  into  $V_2O_5$  layers adopted the  $Zn^{2+}/H_2O$  co-insertion storage mechanism. The  $K_{0.5}V_2O_5$  cathode showed excellent zinc storage performances with a reversible capacity of 397 mAh/g after 100 cycles at 1 A/g and 251 mAh/g after 1000 cycles at 5 A/g [62]. Even when the temperature was as low as  $-20$  °C, the capacity still reached to 241 and 115 mAh/g after 1000 cycles at 1 and 5 A/g, respectively. Density functional theory calculations further demonstrated that the introduction of  $K^+$  promoted the electron migration in the layer and thus boosted the (de)intercalation kinetics of  $Zn^{2+}$ . In addition, there are other metal ions such as  $Li^+$  [63],  $Al^{3+}$  [64],  $Ag^+$  [65],  $Mg^{2+}$  [66],  $Zn^{2+}$  [67] and  $Ca^{2+}$  [68] to be investigated.

## 2.2. Introduction of vanadates in AZIBs

Vanadates as the derivatives of vanadium oxides are widely used in AZIBs owing to various cations. Cations in vanadates as pillars are inserted into the layers of different vanadium oxides to form a variety of vanadates ( $M_xV_3O_8$ ,  $M_xV_2O_7$ ,  $M_xV_6O_{16}$ , and  $M_xV_yO_z$ ) with highly stable structure.

### 2.2.1. Main group trivanadates ( $M_xV_3O_8$ )

The monoclinic  $M_xV_3O_8$  structure is formed by the stacked  $[V_3O_8]$  layers and these layers are connected by M ions. Each  $[V_3O_8]$  layer consists of  $[VO_6]$  octahedrons and  $[VO_5]$  trigonal bipyramids.  $[VO_6]$  octahedron links with  $[VO_5]$  trigonal bipyramids by sharing vertice, resulting in an octahedral vacancy formation in the middle. M ions occupy the vacancy of  $[VO_6]$  octahedron, in which ions are escaped uneasily [69–71]. Among them,  $H_2V_3O_8$  is an important member. H atoms between the layers link with

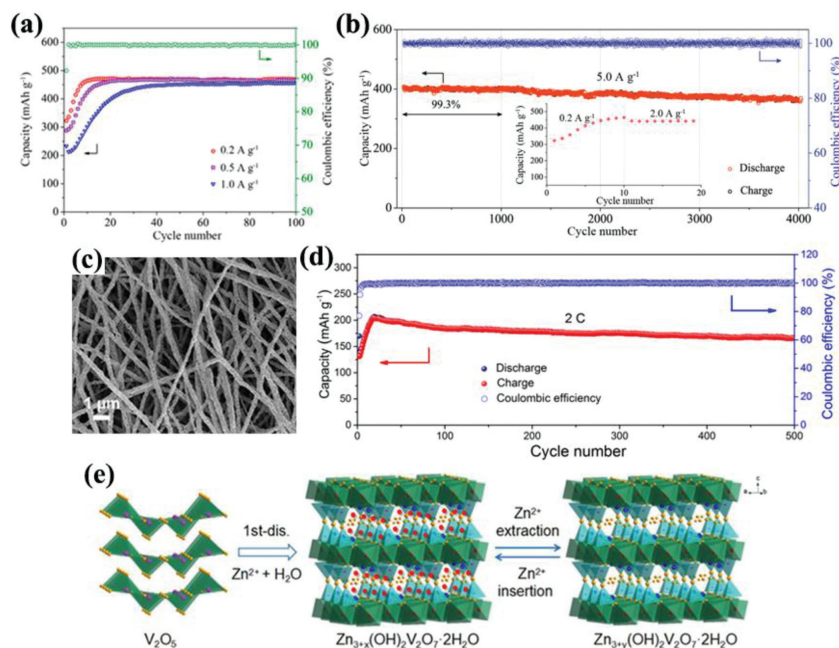


**Fig. 4.** (a) Crystal structure of monoclinic  $V_6O_{13}$ : Three crystallographically nonequivalent vanadium sites in  $V_6O_{13}$  are shown separately. Reproduced with permission [55]. Copyright 2017, American Chemical Society. (b) The charge/discharge galvanostatic intermittent titration technique (GITT) curves of  $V_6O_{13}$  and comparison of  $Zn^{2+}$  diffusion coefficient. (c) Electrochemical impedance spectroscopy (EIS) results of  $V_6O_{13}$ ,  $VO_2$ , and  $V_2O_5$ . (d) The HRTEM image with the corresponding selected area electron diffraction (SAED) pattern at the fully discharged state. (e) Schematic diagram of the highly reversible phase transition during the discharge/charge process of  $V_6O_{13}$ . Reproduced with permission [56]. Copyright 2019, Wiley-VCH. (f, g) The charge distribution and corresponding structure of pristine  $V_6O_{13}$ . (h, i) The charge distribution and corresponding structure of oxygen-deficient  $V_6O_{13}$ . Reproduced with permission [57]. Copyright 2019, Wiley-VCH. (j) Rate performance for P- $V_6O_{13}$  ( $V_6O_{13}$  with  $H_2O$  only) and  $CO_2$ - $V_6O_{13}$  ( $V_6O_{13}$  with a mixture of  $H_2O$  and  $CO_2$ ). (k) Cycling stability and coulombic efficiency for  $CO_2$ - $V_6O_{13}$  and P- $V_6O_{13}$  at 2 A/g. Reproduced with permission [58]. Copyright 2021, American Chemical Society.

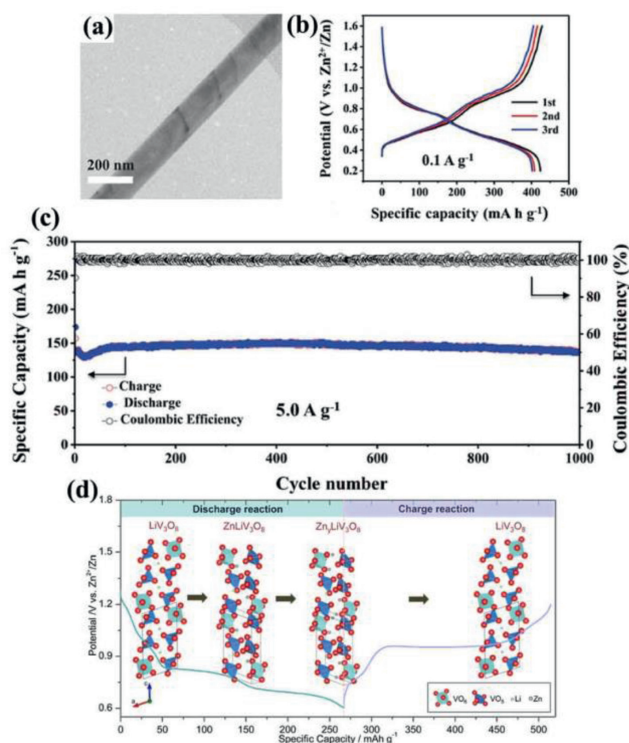
O atoms in  $[VO_6]$  polyhedron by a strong hydrogen bond, which can buffer the expansion/contraction of  $H_2V_3O_8$  structure during the ion insertion/extraction [70]. The ratio of  $V^{5+}/V^{4+}$  is 2:1 in  $H_2V_3O_8$ , which contributes to higher electrical conductivity than other vanadium oxides. For example,  $H_2V_3O_8$  nanowires (Fig. 6a) as cathode delivered a high initial capacity of 423.8 mAh/g at 0.1 A/g (Fig. 6b) and a capacity retention rate of 94.3% after 1000 cycles at 5 A/g (Fig. 6c) [72]. The large interlayer spacing of  $H_2V_3O_8$  contributed to an excellent  $Zn^{2+}$  storage performance. The similar phenomenon occurs in other monovalent ions ( $Li^+$ ,  $Na^+$ ,  $K^+$ ).  $LiV_3O_8$ , similar to the crystal structure of  $H_2V_3O_8$ , also showed good electrochemical performance due to expanding the interlayer spacing [71].  $ZnLiV_3O_8$  transition phase formed at the early stage of discharge when  $Zn^{2+}$  were inserted into the Li-empty sites of

$LiV_3O_8$  (Fig. 6d), and then  $ZnLiV_3O_8$  transformed to  $Zn_yLiV_3O_8$  ( $y > 1$ ) in the continuous intercalation of  $Zn^{2+}$ . However, in the charging process,  $Zn_yLiV_3O_8$  was directly reduced to  $LiV_3O_8$ , suggesting that the intercalation/extraction of  $Zn^{2+}$  was reversible and  $Li^+$  was irreversible.

The ion radius of  $Na^+$  (0.102 nm) is larger than those of  $H^+$  and  $Li^+$  (0.076 nm), so  $NaV_3O_8$  with larger layer spacing ( $\sim 0.71$  nm) can promote ion transfer [73]. For instance, disordered  $NaV_3O_8$  cathode exhibited a capacity of 265 mAh/g at 0.05 A/g in 3 mol/L  $ZnSO_4$  and 117 mAh/g at 0.4 A/g over 2000 cycles in 3 mol/L  $ZnSO_4$ /0.5 mol/L  $Na_2SO_4$  mixed electrolyte [74]. The storage behavior of  $Zn^{2+}$  was sequential two-stage intercalation of  $Zn^{2+}$  and  $H^+$  during discharging. If 1 mol/L  $Na_2SO_4$  was added into 1 mol/L  $ZnSO_4$  solution,  $NaV_3O_8 \cdot 1.5H_2O$  nanoribbons could co-



**Fig. 5.** (a) Galvanostatic cycling performance at 0.2, 0.5 and 1.0 A/g and the corresponding Coulombic efficiency at 0.2 A/g. (b) Long-cycling performance at 5.0 A/g (additional: the capacity evolution in the initial 19 cycles). Reproduced with permission [36]. Copyright 2018, American Chemical Society. (c) Scanning electron microscope (SEM) image of porous V<sub>2</sub>O<sub>5</sub> nanofibers. (d) Long-term cycle performance of V<sub>2</sub>O<sub>5</sub> cathode at 2 C. (e) Schematic of the reaction mechanism of V<sub>2</sub>O<sub>5</sub> cathode. Reproduced with permission [59]. Copyright 2019, Elsevier.



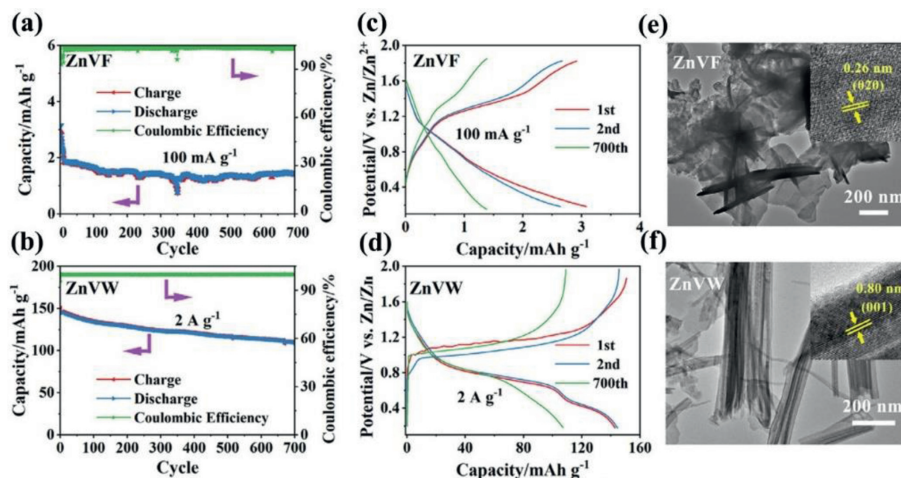
**Fig. 6.** (a) Transmission electron microscopy (TEM) image of H<sub>2</sub>V<sub>3</sub>O<sub>8</sub> nanowires. (b) Charge/discharge profiles at 0.1 A/g of the initial three cycles. (c) Long-term cycle performance of H<sub>2</sub>V<sub>3</sub>O<sub>8</sub> cathode at 5 A/g. Reproduced with permission [72]. Copyright 2017, Wiley-VCH. (d) Schematic mechanism of Zn-intercalated LiV<sub>3</sub>O<sub>8</sub> cathode. Reproduced with permission [71]. Copyright 2017, American Chemical Society.

insert/extract of H<sup>+</sup> and Zn<sup>2+</sup>, and then maintain a reversible capacity of 380 mAh/g at 0.05 A/g and a capacity retention of 82% over 1000 cycles at 4 A/g [75]. If 0.3 mol/L VOSO<sub>4</sub> was added in

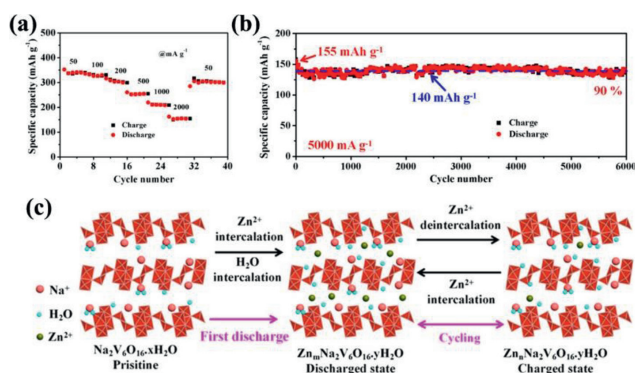
3 mol/L ZnSO<sub>4</sub> electrolyte, fiber-like NaV<sub>3</sub>O<sub>8</sub> cathode underwent a reversible three-ions insertion of VO<sup>2+</sup>, Zn<sup>2+</sup> and H<sup>+</sup> at the discharged state and displayed a high specific capacity of 450 mAh/g at 0.05 A/g and a capacity retention rate of 82% at 0.4 A/g after 500 cycles [76]. VO<sup>2+</sup> carrier with large ion radius (0.16 nm) can still intercalate the layer of host structure and contribute the storage capacity. KV<sub>3</sub>O<sub>8</sub> electrodes with an interlayer distance of ~0.77 nm delivered a discharge capacity of 182 mAh/g at 1.75 A/g with ~82.8% retention of initial capacity for 500 cycles at 1.25 A/g in 1 mol/L Zn(CF<sub>3</sub>SO<sub>3</sub>)<sub>2</sub> electrolyte [77]. The pillar of K<sup>+</sup> in host structure promoted an excellent capacity retention even at high rates due to its larger ion size.

### 2.2.2. Main group polyvanadates (M<sub>x</sub>V<sub>2</sub>O<sub>7</sub>)

The monoclinic α-Zn<sub>2</sub>V<sub>2</sub>O<sub>7</sub> (C2/c) and trigonal Zn<sub>3</sub>V<sub>2</sub>O<sub>7</sub>(OH)<sub>2</sub>·2H<sub>2</sub>O (P3m1) phases are the typical representatives of M<sub>x</sub>V<sub>2</sub>O<sub>7</sub>. [V<sub>2</sub>O<sub>7</sub>] groups consist of a pair of [VO<sub>4</sub>] tetrahedrons both in α-Zn<sub>2</sub>V<sub>2</sub>O<sub>7</sub> and Zn<sub>3</sub>V<sub>2</sub>O<sub>7</sub>(OH)<sub>2</sub>·2H<sub>2</sub>O structure, which align along c-axis to form the layer structure. [ZnO<sub>5</sub>] polyhedron in α-Zn<sub>2</sub>V<sub>2</sub>O<sub>7</sub> is a distorted trigonal bipyramid and [ZnO<sub>6</sub>] polyhedron in Zn<sub>3</sub>V<sub>2</sub>O<sub>7</sub>(OH)<sub>2</sub>·2H<sub>2</sub>O is octahedron. The V-O-V pillars (tetrahedra) separate each Zn-O layer and H<sub>2</sub>O molecules can be randomly accommodated to ensure the facile diffusion of Zn<sup>2+</sup> and electron transport distance because the growth direction of nanowires was parallel to the (002) plane (c-axis). Similarly, Zn<sub>3</sub>V<sub>2</sub>O<sub>7</sub>(OH)<sub>2</sub>·2H<sub>2</sub>O nanowires with porous framework prepared by a simple microwave method improved the intercalation of Zn<sup>2+</sup> [81] and delivered the capacities of 213 and 76 mAh/g at 50 and 3 A/g, respectively, as well as good cycling stability. Cao *et al.* compared the electrochemical performances of 1D nanowires (ZnVW) and 2D nanoflakes (ZnVF) for Zn<sub>3</sub>V<sub>2</sub>O<sub>7</sub>(OH)<sub>2</sub>·2H<sub>2</sub>O (Figs. 7a–f) [78]. The nanowire cathode achieved more excellent discharge capacity of 108 mAh/g after 700 cycles at 2 A/g than that of the nanoflake cathode due to lower polarization, higher electrochemical activity,



**Fig. 7.** (a, b) Charge/discharge cycling profile and coulombic efficiency of ZnVF and ZnVW cathode. (c) Galvanostatic charge/discharge curves of the 1<sup>st</sup>, 2<sup>nd</sup> and 700<sup>th</sup> cycles of ZnVF at the current density of 100 mA/g and (d) ZnVW at the current density of 2 A/g. TEM images of ZnVF (e) and ZnVW (f) after cycling (insets are HRTEM images). Reproduced with permission [78]. Copyright 2021, Elsevier.



**Fig. 8.** (a) Rate performance of the  $\text{Na}_2\text{V}_6\text{O}_{16}\cdot 1.63\text{H}_2\text{O}$  at various current densities. (b) Cycling performances of the  $\text{Na}_2\text{V}_6\text{O}_{16}\cdot 1.63\text{H}_2\text{O}$  at 5000 mA/g. (c) Schematic of the reaction mechanism of  $\text{Na}_2\text{V}_6\text{O}_{16}\cdot 1.63\text{H}_2\text{O}$  cathode. Reproduced with permission [86]. Copyright 2018, American Chemical Society.

and faster ion diffusion capability of 1D materials. Hence, the electrochemical performances of  $\text{M}_x\text{V}_2\text{O}_7$  are highly dependent on preparation methods that influenced its morphology, particle size, and crystallinity beside inherent crystal structure.

### 2.2.3. Hewettite ( $\text{M}_x\text{V}_6\text{O}_{16}\cdot n\text{H}_2\text{O}$ )

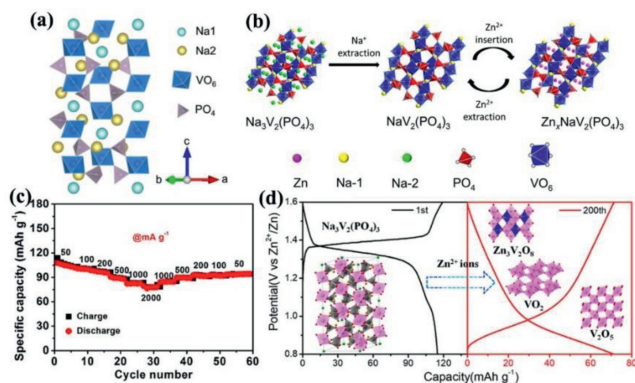
The monoclinic  $\text{M}_x\text{V}_6\text{O}_{16}\cdot n\text{H}_2\text{O}$  comprises  $[\text{V}_3\text{O}_8]$  layers, which are constructed by edge-sharing  $[\text{V}_2\text{O}_8]$  square pyramids and  $[\text{VO}_6]$  octahedrons, and interlayer hydrated M ions connect them together [85]. Much interest focuses on  $\text{Na}_2\text{V}_6\text{O}_{16}\cdot n\text{H}_2\text{O}$  and  $\text{K}_2\text{V}_6\text{O}_{16}\cdot n\text{H}_2\text{O}$ . Hu *et al.* [86] constructed 1D  $\text{Na}_2\text{V}_6\text{O}_{16}\cdot 1.63\text{H}_2\text{O}$  nanowire (Fig. 8a) by hydrothermal method with a high specific capacity of 352 mAh/g at 50 mA/g, a good rate performance and a high retention rate of 90% after 6000 cycles at 5 A/g (Fig. 8b).  $\text{Zn}^{2+}$  and  $\text{H}_2\text{O}$  molecules were simultaneously inserted into the host structure in the first discharge (shown in Fig. 8c), and then only  $\text{Zn}^{2+}$  were reversibly inserted/extracted in the subsequent cycles. 1D  $\text{Na}_2\text{V}_6\text{O}_{16}\cdot 1.63\text{H}_2\text{O}$  nanobelt electrode adopted a similar Zn-storage mechanism and also exhibited superior electrochemical performance including a large discharge capacity of 466 mAh/g at 100 mA/g and excellent cycle stability with capacity retention of 90% over 2000 cycles at 20 A/g [87]. Sambandam *et al.* synthesized  $\text{K}_2\text{V}_6\text{O}_{16}\cdot 2.7\text{H}_2\text{O}$  nanorods, which as cathode achieved a reversible capacity of nearly 180 mAh/g at 6 A/g [88].  $\text{H}_2\text{O}$  molecules co-intercalated with  $\text{Zn}^{2+}$  as lubricant efficiently reduce the “effec-

tive charge” of  $\text{Zn}^{2+}$ , thereby resulting in a higher diffusion coefficient of solvated  $\text{Zn}^{2+}$  and good electrochemical performance. 1D nanomaterials can offer more electrochemically active sites to promote the significant interfacial redox reaction. So the nanostructured morphologies of vanadium-based materials as desirable zinc ion hosts can contribute to improving their electrochemical properties.

Compared to common intercalation metal ions, the existence of hydrogen bonds between  $\text{NH}_4^+$  and  $[\text{V}_3\text{O}_8]$  layer offers a more stable layer structure, contributing to long-term cycling performance. Additionally, the lower molecular weight would provide higher gravimetric specific capacities theoretically. Zhang *et al.* [89] reported that there was the intensive hydrogen bond interaction between H atoms from  $\text{H}_2\text{O}$  and  $\text{NH}_4^+$  and O atoms from  $[\text{V}_3\text{O}_8]$  layer, which value was calculated to be 208.01 meV/Å<sup>2</sup> by first-principles, higher than 49.58 meV/Å<sup>2</sup> of  $\text{V}_2\text{O}_5$ , suppressing the dissolution of  $(\text{NH}_4)_2\text{V}_6\text{O}_{16}\cdot 1.5\text{H}_2\text{O}$ . In the static immersion experiments of  $\text{V}_2\text{O}_5$ ,  $\text{V}_2\text{O}_5\cdot 1.5\text{H}_2\text{O}$ ,  $\text{NH}_4\text{V}_3\text{O}_8$  and  $(\text{NH}_4)_2\text{V}_6\text{O}_{16}\cdot 1.5\text{H}_2\text{O}$  cathodes, only  $(\text{NH}_4)_2\text{V}_6\text{O}_{16}\cdot 1.5\text{H}_2\text{O}$  materials remained colorless after 200 days, suggesting the strong stability in the electrolyte. Furthermore, Wang *et al.* [90] presented  $(\text{NH}_4)_2\text{V}_6\text{O}_{16}\cdot 1.5\text{H}_2\text{O}$  nanoribbons, which not only contributed to a high reversible capacity of 479 mAh/g at 0.1 A/g but also remained the specific capacity of 152 mAh/g at 5 A/g even after 3000 cycles. The results of *ex-situ* XRD, FTIR, XPS and HRTEM verified that the electrochemical reaction mechanism of  $(\text{NH}_4)_2\text{V}_6\text{O}_{16}\cdot 1.5\text{H}_2\text{O}$  electrode was as follows: Zinc ions were intercalated into  $(\text{NH}_4)_2\text{V}_6\text{O}_{16}\cdot 1.5\text{H}_2\text{O}$  along with a new phase of  $\text{Zn}_3(\text{OH})_2\text{V}_2\text{O}_7\cdot 2\text{H}_2\text{O}$  formation during the discharge process and were extracted from  $(\text{NH}_4)_2\text{V}_6\text{O}_{16}\cdot 1.5\text{H}_2\text{O}$  accompanied by the new phase disappearing during the charging process.

### 2.3. Introduction of alkali vanadium phosphates ( $\text{M}_x\text{V}_2(\text{PO}_4)_3$ , M = Li, Na) in AZIBs

$\text{M}_x\text{V}_2(\text{PO}_4)_3$  (M = Li, Na) structure is composed of  $[\text{VO}_6]$  octahedrons and  $[\text{PO}_4]$  tetrahedrons by sharing all vertices to form the “lantern”  $[\text{V}_2(\text{PO}_4)_3]$  unit framework, where M atoms occupy the voids of tetrahedrons and octahedrons (Fig. 9a). The open frame structure can endure the significant volume change (radius of  $\text{Na}^+$  (0.102 nm) and  $\text{Li}^+$  (0.076 nm) vs.  $\text{Zn}^{2+}$  (0.074 nm)) in the ion insertion or extraction process [91–97]. Monoclinic  $\text{Li}_3\text{V}_2(\text{PO}_4)_3$  ( $P2_1/n$ , LVP) and rhombohedral  $\text{Na}_3\text{V}_2(\text{PO}_4)_3$  ( $R\bar{3}c$ , NVP) cathodes not only provide a robust structure but also a high working volt-



**Fig. 9.** (a) Crystal structure of the NVP structure. Reproduced with permission [100]. Copyright 2020, American Chemical Society. (b) Schematic diagram for phase transition of Na<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> cathode during cycling. Reproduced with permission [29]. Copyright 2016, Elsevier. (c) Rate performance of the NVP@rGO at various current densities. Reproduced with permission [99]. Copyright 2019, Elsevier. (d) The decomposition mechanism of Na<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> during battery cycling. Reproduced with permission [102]. Copyright 2021, American Chemical Society.

age (~1.8 V vs. Zn<sup>2+</sup>/Zn). Zhao *et al.* [98] compared the electrochemical mechanisms of Li<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> (LVP) and Na<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> (NVP) cathodes in mixed aqueous electrolyte (1 mol/L Li<sub>2</sub>SO<sub>4</sub> and 2 mol/L ZnSO<sub>4</sub>). NVP cathode experienced Na<sup>+</sup> and Li<sup>+</sup> co-insertion while only two Li<sup>+</sup> insertion for LVP cathode. Zn<sup>2+</sup> precipitated on the surface of zinc metal, leading to initial discharge capacities of 128 and 96 mAh/g at 0.2 C for LVP and NVP cathodes, respectively. Compared with the low charge of Li<sup>+</sup>/Na<sup>+</sup>, Zn<sup>2+</sup> with strong electrostatic interaction force was difficult to be inserted into the LVP/NVP lattice. However, Zn<sup>2+</sup> could intercalate Na-deficit NVP structure (NaV<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub>) through NVP to form Zn<sub>x</sub>NaV<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> in the first discharge process and de-intercalate after charging shown in Fig. 9b [29], resulting in a reversible capacity of 97 mAh/g at 0.5 C and a capacity retention rate of 74% after 100 cycles in 0.5 mol/L Zn(CH<sub>3</sub>COO)<sub>2</sub> electrolyte. If AZIBs assembled with NVP@reduced graphene oxide (NVP@rGO) microspheres cathode and 2 mol/L Zn(CF<sub>3</sub>SO<sub>3</sub>)<sub>2</sub> electrolyte [99], Zn<sup>2+</sup> and Na<sup>+</sup> were simultaneously inserted into NVP structure tested by *ex-situ* XPS and XRD. Galvanostatic intermittent titration technique (GITT) test showed that the divalent Zn<sup>2+</sup> had higher diffusion coefficient than monovalent Na<sup>+</sup>. The complete electrochemical reaction equation was as follows: Na<sub>x</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> + zZn<sup>2+</sup> + yNa<sup>+</sup> + (2z+y)e<sup>-</sup> ↔ Zn<sub>z</sub>Na<sub>(x+y)</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub>. The specific capacity of NVP@rGO cathode reached up to 74 mAh/g at 500 mA/g after 200 cycles and its rate performance was also excellent (107 mAh/g at 50 mA/g and 82 mAh/g at 2 A/g) (Fig. 9c). Ko *et al.* [100] proposed a quasi-two-stage Na<sup>+</sup> and Zn<sup>2+</sup> insertion mechanism based on the analysis results of synchrotron XRD and Rietveld refinement using porous NVP as cathode and 0.5 mol/L Zn(CH<sub>3</sub>COO)<sub>2</sub> as electrolyte. The formation of Na-deficit NVP structure (NaV<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub>) at the initial charging stage resulted in the predominant intercalation of Na<sup>+</sup> followed by the Zn<sup>2+</sup> intercalation into Na2 (18e site) place of NVP, which was more active than Na1(6b site) place. When discharged to 0.6 V, Zn<sub>0.25</sub>NaV<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> phase with good electrochemical reversibility formed. However, the reason for Zn<sup>2+</sup> occupying only Na2 site was still unknown. Hu *et al.* [101] revealed the Na<sup>+</sup> and Zn<sup>2+</sup> mixed occupation at both Na1 and Na2 sites of Zn<sub>x</sub>NaV<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> based on experimental and theoretical methods, which improved the conductivity, crystal structure and structural stability of Zn<sub>x</sub>NaV<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> after Zn<sup>2+</sup> insertion. Na1 sites were activated due to the concerted migration of Na<sup>+</sup>/Zn<sup>2+</sup>. Recently, Li *et al.* [102] demonstrated that the NASICON-type compounds were not suitable for AZIB because of their structure decomposition during the long cycles (Fig. 9d) after comparing the struc-

ture stability of Na<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> and Na<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>2</sub>F<sub>3</sub> cathodes in 1 mol/L Zn(CF<sub>3</sub>SO<sub>3</sub>)<sub>2</sub>. During cycling, Na<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>3</sub> decomposed into Zn<sub>3</sub>V<sub>2</sub>O<sub>8</sub>, V<sub>2</sub>O<sub>5</sub>, and V<sub>2</sub>O, while Na<sub>3</sub>V<sub>2</sub>(PO<sub>4</sub>)<sub>2</sub>F<sub>3</sub> decomposed into V<sub>2</sub>O<sub>5</sub>, VPO<sub>5</sub>, and Zn<sub>3</sub>(OH)<sub>2</sub>V<sub>2</sub>O<sub>7</sub>·2H<sub>2</sub>O, greatly reducing the stability of NASICON-type compounds.

#### 2.4. Introduction of other vanadium-based materials in AZIBs

Vanadium disulfide (VS<sub>2</sub>) is a representative member of transition metal dichalcogenide, which possesses the unique chain layered structure analogous to graphite. V atoms and S atoms in VS<sub>2</sub> are covalently bonded, and neighboring layers (S-V-S) with a large interlayer distance of 0.58 nm are connected by weak van der Waals interaction, which can accommodate more the guest ion storage of Zn<sup>2+</sup>, Al<sup>3+</sup> and Mg<sup>2+</sup> [103–107]. Even if these guest ions are intercalated in the host structure, the structure of VS<sub>2</sub> is not significantly broken [108,109]. For instance, He *et al.* [26] firstly investigated the insertion mechanism of Zn<sup>2+</sup> for VS<sub>2</sub> nanosheet by means of *in-situ* Raman, *ex-situ* XRD and *ex-situ* XPS tests. The phase transitions from VS<sub>2</sub> to Zn<sub>0.09</sub>VS<sub>2</sub> and then to Zn<sub>0.23</sub>VS<sub>2</sub> occurred within a voltage range of 0.65–0.82 and 0.45–0.65 V during the discharge process, respectively. The interlayer expansion of VS<sub>2</sub> along (002) after Zn<sup>2+</sup> inserting is only 1.73%. Hence VS<sub>2</sub> nanosheet cathode for AZIBs provides a reversible specific capacity of 190.3 mAh/g at 0.05 A/g under the voltage window of 0.4–1.0 V. Even at 0.5 A/g, the first capacity retention rate reached 98% after 200 cycles. But in fact, the narrow voltage window (0.4–1.0 V vs. Zn<sup>2+</sup>/Zn) limited the energy density of VS<sub>2</sub>. Yu *et al.* [110] increased the working potential by *in-situ* fabricating heterostructural VS<sub>2</sub>/VO<sub>x</sub> materials. The average discharge voltage of VS<sub>2</sub>/VO<sub>x</sub> cathode was 0.9 V (vs. Zn/Zn<sup>2+</sup>), which is 0.25 V higher than that of the pristine VS<sub>2</sub> cathode. So the composite electrode provided a reversible capacity of 150 mAh/g at 0.1 A/g. Even at 1 A/g, the capacity retention rate reached 75% after 3000 cycles. Liu *et al.* [111] adopted N-doped carbon as the conductive supports instead of VO<sub>x</sub> to improve the chemical stability and long-cycle performance with the help of strong interfacial interaction between VS<sub>2</sub> and N-doped carbon. The resulting cathode displayed a high specific capacity of 203 mAh/g at 50 mA/g and long-term cycling stability with a capacity retention of 97% after 600 cycles at 1 A/g.

Monoclinic VS<sub>4</sub> (I2/c) as an analog of VS<sub>2</sub> is a unique 1D atomic-chain structure bonded by weak van der Waals forces, which is consisted of V<sup>4+</sup> coordinated to sulfur dimers (S<sub>2</sub><sup>2-</sup>). VS<sub>4</sub> with more S atoms shows larger interlayer space (0.583 nm) than that of VS<sub>2</sub> [112–115]. Qin *et al.* [116] prepare VS<sub>4</sub>@rGO composite by the hydrothermal method, which displayed a capacity as high as 180 mAh/g at 1 A/g after 165 cycles and a capacity retention of 93.3%. During the battery charge/discharge, a conversion reaction occurred between VS<sub>4</sub> and Zn<sub>3</sub>(OH)<sub>2</sub>V<sub>2</sub>O<sub>7</sub>·2H<sub>2</sub>O.

Hexagonal vanadium diselenide (VSe<sub>2</sub>, P3m1) is also a typical layered structure, where V atoms and Se atoms combine with covalent bonds to form the Se-V-Se sandwich structure. And the layers connect each other by van der Waals forces along c-axis direction. The electronegativity of Se is lower than those of O and S, which reduced the electrostatic interaction between the intercalation ions and the host structure and lowered the electron migration barrier [117]. Wang *et al.* [118] firstly presented VSe<sub>2</sub> cathode with a large interlayer spacing of 0.61 nm and showed a discharge storage capacity of 250.6 mAh/g at 200 mA/g and a reversible specific capacity of 132.6 mAh/g even at a high current density of 5 A/g. Bai *et al.* [119] adopt defect engineering to fabricate the stainless steel (SS)-supported VSe<sub>2</sub> nanosheets with defects to improve the conductivity and fasten the ion transmission speed ( $D_{Zn^{2+}} \approx 10^{-8}$  cm<sup>2</sup>/s). Therefore, the synergistic effects of selenium defects and self-supporting structure improved

**Table 1**  
The typical vanadium-based cathodes and their electrochemical properties for AZIBs.

Structure characteristic	Cathode	Electrolyte	Specific capacity (Current density)	Capacity retention (Cycles numbers)	Mechanism	Refs.
1D tunnel	VO <sub>2</sub> (B)	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	357 mAh/g (0.1 A/g)	91.2% (300)	Zn <sup>2+</sup> insertion	[46]
	VO <sub>2</sub> (B)	ZnSO <sub>4</sub>	353 mAh/g (1 A/g)	75% (945)	H <sup>+</sup> insertion	[49]
	VO <sub>2</sub> (M)	ZnSO <sub>4</sub>	248 mAh/g (2 A/g)	84.5% (5000)	Zn <sup>2+</sup> /H <sup>+</sup> co-insertion	[50]
	VO <sub>2</sub> (D)	ZnSO <sub>4</sub>	408 mAh/g (0.1 A/g)	48.3% (20000)	Zn <sup>2+</sup> /H <sup>+</sup> co-insertion	[51]
	VS <sub>4</sub> @rGO	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	180 mAh/g (1 A/g)	93.3% (165)	conversion reactions/ Zn <sup>2+</sup> insertion	[116]
	V <sub>6</sub> O <sub>13</sub>	Zn(CH <sub>3</sub> F <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	400 mAh/g (0.2 A/g)	86% (2000)	Zn <sup>2+</sup> insertion	[57]
	CO <sub>2</sub> -V <sub>6</sub> O <sub>13</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	471 mAh/g (0.1 A/g)	80% (4000)	Zn <sup>2+</sup> insertion	[58]
2D layers	V <sub>2</sub> O <sub>5</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	470 mAh/g (0.2 A/g)	91.1% (4000)	Zn <sup>2+</sup> /H <sub>2</sub> O co-insertion	[36]
	V <sub>2</sub> O <sub>5</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	319 mAh/g (0.02 A/g)	81% (500)	conversion reactions/ Zn <sup>2+</sup> insertion	[59]
	V <sub>2</sub> O <sub>5</sub> -Ti	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	503.1 mAh/g (0.1 A/g)	86% (700)	Zn <sup>2+</sup> insertion	[60]
	Na <sub>0.33</sub> V <sub>2</sub> O <sub>5</sub>	Zn(CH <sub>3</sub> F <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	367.1 mAh/g (0.1 A/g)	93% (1000)	Zn <sup>2+</sup> insertion	[61]
	K <sub>0.5</sub> V <sub>2</sub> O <sub>5</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	486 mAh/g (0.1 A/g)	98% (1000)	Zn <sup>2+</sup> /H <sub>2</sub> O co-insertion	[62]
	H <sub>2</sub> V <sub>3</sub> O <sub>8</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	423.8 mAh/g (0.1 A/g)	94.3% (1000)	Zn <sup>2+</sup> insertion	[72]
	LiV <sub>3</sub> O <sub>8</sub>	ZnSO <sub>4</sub>	256 mAh/g (0.016 A/g)	75% (65)	Zn <sup>2+</sup> insertion	[71]
	NaV <sub>3</sub> O <sub>8</sub>	ZnSO <sub>4</sub> /NaSO <sub>4</sub>	265 mAh/g (0.05 A/g)	78% (2000)	Zn <sup>2+</sup> /H <sup>+</sup> co-insertion	[74]
	NaV <sub>3</sub> O <sub>8</sub> ·1.5H <sub>2</sub> O	ZnSO <sub>4</sub> /Na <sub>2</sub> SO <sub>4</sub>	380 mAh/g (0.05 A/g)	82% (1000)	Zn <sup>2+</sup> /H <sup>+</sup> co-insertion	[75]
	KV <sub>3</sub> O <sub>8</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	249 mAh/g (0.025 A/g)	~82.8% (500)	Zn <sup>2+</sup> insertion	[77]
	Zn <sub>2</sub> V <sub>2</sub> O <sub>7</sub>	ZnSO <sub>4</sub>	203 mAh/g (0.3 A/g)	85% (1000)	Zn <sup>2+</sup> insertion	[80]
		ZnSO <sub>4</sub>	213 mAh/g (0.05 A/g)	68% (300)	Zn <sup>2+</sup> insertion	[81]
	Zn <sub>3</sub> V <sub>2</sub> O <sub>7</sub> (OH) <sub>2</sub> ·2H <sub>2</sub> O	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	352 mAh/g (0.05 A/g)	90% (6000)	Zn <sup>2+</sup> insertion	[86]
	Na <sub>2</sub> V <sub>6</sub> O <sub>16</sub> ·1.63H <sub>2</sub> O	ZnSO <sub>4</sub> /Na <sub>2</sub> SO <sub>4</sub>	466 mAh/g (0.1 A/g)	90% (2000)	Zn <sup>2+</sup> insertion	[87]
	K <sub>2</sub> V <sub>6</sub> O <sub>16</sub> ·2.7H <sub>2</sub> O	ZnSO <sub>4</sub>	329.6 mAh/g (0.2 A/g)	~82% (500)	Zn <sup>2+</sup> /H <sub>2</sub> O co-insertion	[88]
		ZnSO <sub>4</sub>	442.2 mAh/g (0.1 A/g)	91.2% (5000)	Zn <sup>2+</sup> insertion	[89]
	(NH <sub>4</sub> ) <sub>2</sub> V <sub>6</sub> O <sub>16</sub> ·1.5H <sub>2</sub> O	ZnSO <sub>4</sub>	190.3 mAh/g (0.05 A/g)	98.0% (200)	Zn <sup>2+</sup> insertion	[26]
	VS <sub>2</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	203 mAh/g (0.05 A/g)	97% (600)	Zn <sup>2+</sup> insertion	[111]
	VS <sub>2</sub> @N-doped C	ZnSO <sub>4</sub>	250.6 mAh/g (0.2 A/g)	83% (800)	Zn <sup>2+</sup> insertion	[118]
	VSe <sub>2</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	265.2 mAh/g (0.2 A/g)	87.8% (1800)	Zn <sup>2+</sup> insertion	[119]
3D frameworks	V <sub>2</sub> O <sub>3</sub> @C	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	350 mAh/g (0.1 A/g)	90% (4000)	Zn <sup>2+</sup> /H <sub>2</sub> O co-insertion	[43]
	V <sub>2</sub> O <sub>3</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	382.5 mAh/g (0.4 A/g)	97.3% (800)	Zn <sup>2+</sup> insertion	[44]
	V <sub>2</sub> O <sub>3</sub>	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	625 mAh/g (0.1 A/g)	100% (10000)	conversion reactions/ Zn <sup>2+</sup> insertion	[45]
	Na <sub>3</sub> V <sub>2</sub> (PO <sub>4</sub> ) <sub>3</sub>	Zn(CH <sub>3</sub> COO) <sub>2</sub>	97 mAh/g (0.05 A/g)	74% (100)	Zn <sup>2+</sup> insertion	[29]
	Na <sub>3</sub> V <sub>2</sub> (PO <sub>4</sub> ) <sub>3</sub> /rGO	Zn(CF <sub>3</sub> SO <sub>3</sub> ) <sub>2</sub>	114 mAh/g (0.05 A/g)	75% (200)	Zn <sup>2+</sup> /Na <sup>+</sup> co-insertion	[99]

the VSe<sub>2-x</sub>-SS structure stability and increased the specific capacity (265 mAh/g).

### 3. Conclusions and outlooks

Generally, the zinc-ion storage mechanisms of vanadium-based cathodes are the crystal structure-related theory. Table 1 lists the

electrochemical performance and energy storage mechanism of vanadium-based cathodes. The storing Zn<sup>2+</sup> ways of the monoclinic VO<sub>2</sub>, V<sub>6</sub>O<sub>13</sub> and VS<sub>4</sub> phases with 1D-tunnel structure heavily depend on different lattice types. The VO<sub>2</sub>(D) and VO<sub>2</sub>(M) cathodes with monoclinic-P lattice structure adopt the Zn<sup>2+</sup>/H<sup>+</sup> co-insertion mechanism. The VO<sub>2</sub>(B) and V<sub>6</sub>O<sub>13</sub> phases with monoclinic-C lattice structures are inclined to the Zn<sup>2+</sup> insertion mechanism. How-

ever, in other monoclinic-C lattice structure ( $I2/c$ ),  $VS_4$  cathode prefers to the conversion reactions and  $Zn^{2+}$  insertion mechanism.

Most layered vanadium-based materials such as  $V_2O_5$ ,  $VS_2$ ,  $VSe_2$ ,  $Zn_3V_2O_7(OH)_2 \cdot 2H_2O$  and  $Na_2V_6O_{16} \cdot 2.14H_2O$  provide 2D diffusion channels of facilitating  $Zn^{2+}$  insertion. The guest ions intercalated into layered  $V_2O_5$ -type compounds act as pillars to stabilize the layered structure, contributing more superior cycling performance than that of the tunnel structure in Table 1. Their expanding layer space can accommodate  $Zn^{2+}$  and  $H_2O$  co-insertion. Moreover,  $H_2O$  molecules not only act as a charge shielding medium to stabilize structure, but also reduce the "effective charge" of  $Zn^{2+}$  and promote the intercalation rate of  $Zn^{2+}$ .

The framework-structured  $V_2O_3$  and NASICON-type compounds have various interpenetrating 3D diffusion channels, which can accommodate more  $Zn^{2+}$ . Hence the framework-structured cathodes with 3D tunnel can adopt all of the above-mentioned Zn-storage mechanisms. In addition, NASICON-type compounds can also permit  $Zn^{2+}/Na^+$  co-insertion mechanism due to involving the  $Na^+$  de/intercalating.

The goal of this review is to summarize the recent progress of the vanadium-based compound family, including vanadium oxide, vanadates, alkali vanadium phosphates and other vanadium-based materials, and to present the relationship between the structural features and  $Zn^{2+}$  storage mechanisms, which are crucial for designing and preparing high-energetic materials. Although vanadium-based materials have made impressive progress in AZIBs cathodes, suitable anodes, electrolytes, current collectors and binders are equally important for the development of AZIBs. Hence, accelerating the development of high-performance AZIBs needs to pay enough attention to the following aspects.

- (1) The dissolution of vanadium-based compounds in electrolytes during cycling causes the capacity fading and cycling stability reducing. Modifying electrolytes, constructing the integrated electrode and designing the cathodes with stable structure can address the above-mentioned shortcomings.
- (2) The inherent low operating voltage of vanadium-based compounds hinders their practical applications. Introducing the electron-withdrawing groups on vanadium-based compounds and higher electronegative atom substitution or exploring more advanced materials could increase the voltage platform.
- (3) The mechanism for energy storage plays a crucial role in guiding the design of the cathode materials. Many energy storage mechanisms have been put forward, but they do not reach an agreement so far. Therefore, more and more high-resolution *in-situ* characterization technologies need to be applied to provide further proof to elucidate the real storage mechanisms, which is of great significance to the application of vanadium-based materials in AZIBs cathodes.
- (4) The inherently-poor electrical conductivity of vanadium-based materials causes their distinct volume changes during cycling. The highly-conductive additives such as carbon-based materials are an effective strategy to address this problem. Beside, metal element doping modification and defect engineering can improve electrochemical performance by boosting the chemical environment of vanadium-based compounds.
- (5) Vanadium-based compounds with layered structures are gradually damaged due to the repeated insertion/extraction of  $Zn^{2+}$ . The design and synthesis of core-shell and hollow structures will help vanadium-based compounds to maintain the structural stability.

#### Declaration of competing interest

We have no conflicts of interest to declare.

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